# **Photomicrosensor (Transmissive)**

# EE-SJ8-B

# Slot / PCB mounting Type (Slot width: 8 mm)

- 18-mm-tall model with a deep slot.
- High resolution with a 0.5-mm-wide aperture.



(1)

Be sure to read Safety Precautions on page 3.



# **Model Number Structure**

EE-S J 8 - E

(1)

2) (

1

(3)

(4)

Photomicrosensor

Transmissive

Distance between emitter and detector

PCB mounting

# **Ordering Information**

## **Photomicrosensor**

Appearance	Sensing method	Connecting method	Sensing distance	Aperture size (H $ imes$ W) (mm)	Output type	Model	Minimum packing unit (Unit: pcs)
6.5	Transmissive (slot type)	PCB mounting	8 mm (slot width)	Both emitting side and detecting side 2.1 × 0.5	Phototransistor	EE-SJ8-B	1

Note: Order in multiples of minimum packing unit.

# **Ratings, Characteristics and Exterior Specifications**

# Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rated value	Unit
Emitter				
	Forward current	lF	50 *1	mA
	Pulse forward current	IFP	1 *2	Α
	Reverse voltage	VR	4	V
Detector				
	Collector-Emitter voltage	Vceo	30	V
	Emitter-Collector voltage	VECO		
	Collector current	lc	20	mA
	Collector dissipation	Pc	100 *1	mW
Ambient temperature				
	Operating	Topr	-25 to 85	°C
	Storage	Tstg	-30 to 100	°C
Soldering temperature		Tsol	260 *3	°C

<sup>\*1.</sup> Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

# **Exterior Specifications**

Connecting method	Weight (g)	Material	
Connecting method	weight (g)	Case	
PCB mounting	1.62	Polycarbonate	

# Electrical and Optical Characteristics (Ta = 25°C)

Item				Value			
		Symbol				Unit	Condition
			MIN.	TYP.	MAX.		
Emitter							
	Forward voltage	VF		1.2	1.5	V	IF = 30 mA
	Reverse current	IR		0.01	10	μΑ	V <sub>R</sub> = 4 V
	Peak emission wavelength	λР		940		nm	IF = 20 mA
Det	ector						
	Light current	lι	0.05		5	mA	I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 10 V
	Dark current	lo		2	200	nA	Vce = 10 V, 0 l/x
	Leakage current	ILEAK					
	Collector-Emitter saturated voltage	Vce (sat)					
	Peak spectral sensitivity wavelength	λР		850		nm	Vce = 10 V
Rising time		tr		4		μs	$\begin{aligned} &\text{Vcc} = 5 \text{ V}, \\ &\text{RL} = 100 \Omega \\ &\text{IL} = 5 \text{ mA} \end{aligned}$
Falling time		tf		4		μs	$\begin{aligned} &\text{Vcc} = 5 \text{ V}, \\ &\text{RL} = 100 \Omega \\ &\text{IL} = 5 \text{ mA} \end{aligned}$

<sup>\*2.</sup> The pulse width is 10 μs maximum with a frequency of 100 Hz.

<sup>\*3.</sup> Complete soldering within 10 seconds.

# **Engineering Data (Reference value)**

Fig 1. Forward Current vs. Collector **Dissipation Temperature Rating** 

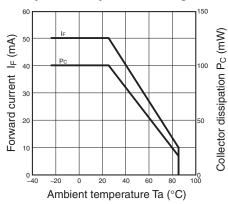


Fig 4. Light Current vs. Collector-**Emitter Voltage Characteristics** (Typical)

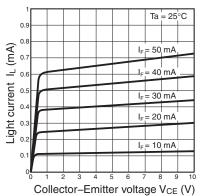


Fig 7. Response Time vs. Load **Resistance Characteristics (Typical)** 

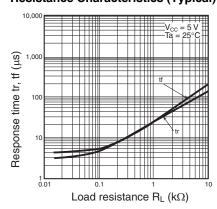


Fig 2. Forward Current vs. Forward Voltage Characteristics (Typical)

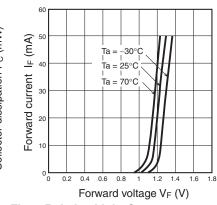


Fig 5. Relative Light Current vs. **Ambient Temperature Characteristics** (Typical)

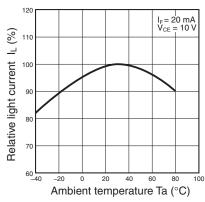


Fig 8. Sensing Position Characteristics Fig 9. Response Time Measurement (Typical)

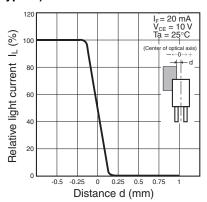


Fig 3. Light Current vs. Forward **Current Characteristics (Typical)** 

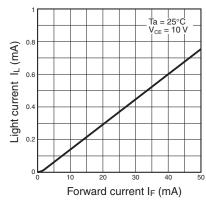
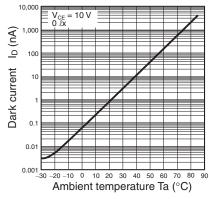
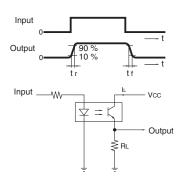


Fig 6. Dark Current vs. Ambient **Temperature Characteristics (Typical)** 



Circuit



# **Safety Precautions**

To ensure safe operation, be sure to read and follow the Instruction Manual provided with the Sensor.

# **CAUTION**

This product is not designed or rated for ensuring safety of persons either directly or indirectly. Do not use it for such purposes.



#### **Precautions for Correct Use**

Do not use the product in atmospheres or environments that exceed product ratings.

#### Precautions for Safe Use

Do not use the product with a voltage or current that exceeds the rated range.

Applying a voltage or current that is higher than the rated range may result in explosion or fire.

Do not miswire such as the polarity of the power supply voltage.

Otherwise the product may be damaged or it may burn.

This product does not resist water. Do not use the product in places where water or oil may be sprayed onto the product.

# **Dimensions and Internal Circuit**

(Unit: mm)

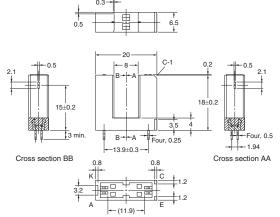
#### **Photomicrosensor**

## EE-SJ8-B

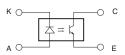


Aperture size (H×W)

Emitter	Detector		
2.1 × 0.5	2.1 × 0.5		



## Internal circuit



Terminal No.	Name
Α	Anode
K	Cathode
С	Collector
E	Emitter

Unless otherwise specified, the tolerances are as shown below.

	Dimensions	Tolerance
	3 mm max.	±0.3
	3 < mm ≤ 6	±0.375
	6 < mm ≤ 10	±0.45
	10 < mm ≤ 18	±0.55
Ī	18 < mm ≤ 30	±0.65

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